NSN 5961-01-014-9684

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View Online at https://aerobasegroup.com/nsn/5961-01-014-9684 **Inclosure Material:** Metal **Overall Length:** 0.406 inches **Overall Diameter:** 0.828 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.875 inches **Thread Size:** 0.312 inches **Criticality Code Justification:** Feat **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 150.0 breakdown voltage, collector-to-base, emitter open and 140.0 breakdown voltage, collector-to-emitter, base open and 7.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 10.00 amperes source cutoff current and 20.00 amperes source cutoff current **Power Rating Per Characteristic:** 114.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Item must comply with rqmt of desc production standard no. L01938; junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 3 tab, solder lug Shelf Life:

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N/a

Unit Of Measure:

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Demilitarization:

No

Fiig:

A110a0